

TSTE19

Power Electronics

Examination (TEN1)

Time: Wednesday 13th January 2016 at 8:00 – 12:00

Place: U4/U6

Responsible teacher: Tomas Jonsson

Will visit the exam location at 8:45 and 10.

Number of tasks: 6

Number of pages: 8

Allowed aids: Calculator

Total points: 70

Notes: A pass on the exam requires approx. 30 points.

Describe your calculations clearly and detailed, explaining

your methods, assumptions and equations used.

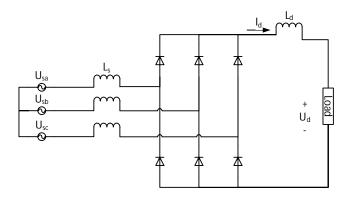


Figure 1

a) A three phase diode rectifier according to Figure 1 has inductance, L_s , on the ac-side-and L_d on the dc-side. Which inductance shall be large in order to obtain continuous current through the dc-load.

b) List the three most important parameters that defines the commutation of

(3)

(2)

(2)

(2)

c) In a DC/DC converter, inductance is commonly used for energy transfer between low and high-voltage sides. If the average voltage across the inductance is greater than zero during a time interval, what can you say about the shape of the inductor current during this interval?

current between two diodes in a rectifier as of Figure 1. Give a short



motivation why.

Figure 2

- d) What device parameters are required to determine the conduction losses of a MOSFET if the drain current is known?
- e) List three types of semiconductors with turn-off capability. (3)



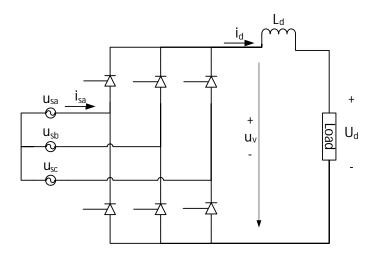


Figure 3

losses of the thyristor converter.

A three phase thyristor rectifier as shown by Figure 3 is connected to a three phase voltage source with the phase-phase voltage Us=410 Vrms. The commutation inductance can be neglected.

a) Draw the waveform of the converter dc-side voltage u_v (before the inductor L_d) for a firing angle α=30 deg.
b) Draw the waveform of the source current, i_{sa}, in one phase.
c) Determine the displacement power factor.
d) Calculate the dc-load voltage, U_d, and dc-power considering a resistive load of 25 ohm.
e) Calculate the fundamental frequency source rms current (i_{sa}). Assume zero



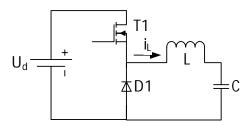


Figure 4

In the buck converter in Figure 4, the current i_L is continuous with an average of 5 A, and with a negligible ripple magnitude. The MOSFET T1 is operated with a switching frequency $f_{sw} = 120$ kHz and a duty cycle in order to keep the capacitor voltage at 10 V for an input voltage $U_d = 24$ V.

(2)a) Determine the duty cycle of the MOSFET T1. b) Calculate the conduction losses in the MOSFET T1 if the on-state (3) resistance $R_{ds(on)} = 0.05$ ohm. c) Calculate the turn-on losses in the MOSFET T1 if the rise time of the (3) drain current is 40 ns. Current rises linearly and voltage is constant. (3)d) Calculate the turn-off losses in the MOSFET T1 if the fall time of the drain current is 60 ns. Current rises linearly and voltage is constant. (5) e) Determine the maximum allowed thermal resistance of the heatsink (R_{thHA}) for the MOSFET T1 in order to keep the heatsink temperature, $T_H \le 60$ °C and the junction temperature, $T_J \le 100$ °C. The MOSFET has a thermal resistance R_{thJH} = 45.0 °C/W. The ambient temperature, $T_A = 25$ °C. Note: T_H or T_J will equal the given limits, the other shall be lower.



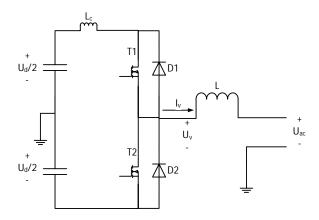


Figure 5

A half-bridge voltage source converter is connected between a dc-source and an acload as shown by Figure 5. The control of the switched output voltage is done through pulse width modulation (PWM) with a switching frequency f_{sw} =950 Hz, in order to obtain a 50 Hz voltage component with a defined magnitude.

- a) What is the minimum required dc-side voltage, U_d , required if the magnitude of the 50 Hz voltage component shall be 24V rms when the amplitude modulation ratio, ma=0.9.
- b) Calculate the current ripple in the output current, I_v , during the time interval shown in Figure 6. The time is defined based on the switching frequency cycle, $T_{sw}=1/f_{sw}$. During this time interval $U_{ac}=0.4^*U_d$, for the value of U_d calculated in a). The inductance L=3 mH. The initial current $I_v(t=0)=0$.

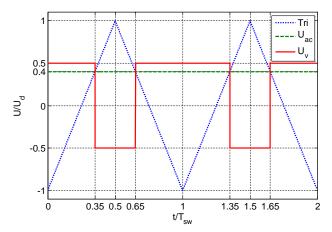


Figure 6



(5)

(5)

(4)

(4)

Question 5

The half-bridge converter in Figure 5 has a parasitic inductance, L_c , between the dc-source and the half-bridge. Figure 7 the switching waveform of the current through the MOSFET switch T1. The current I_v =12 A flows through L out of the converter.

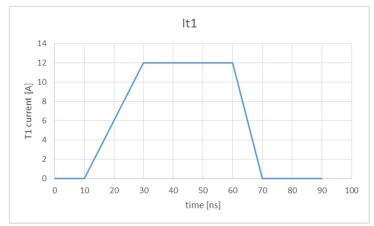


Figure 7

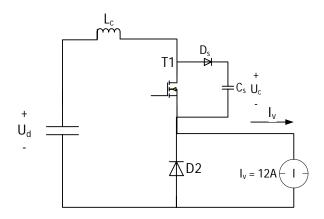
- a) Draw the waveform of the voltage across MOSFET T1, related to the current given in Figure 7 and considering the inductance L_c =40 nH. The dc-voltage U_d =110 V.
- b) What is the peak voltage across the MOSFET?



(4)

Question 6

A parallel capacitive snubber shall be designed for limitation of the peak voltage across the MOSFET switches of a half-bridge converter. The snubber, as shown by Figure 8, consists of a diode D_s , which will charge the snubber capacitor C_s during over-voltage but prevent discharge when the MOSFET turns on. The dc-side voltage U_d =110 V. The design shall be based on the switching conditions related to a load current I_V = 12 A.



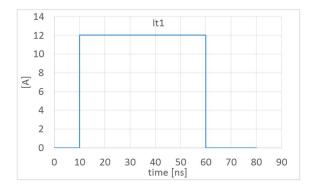


Figure 8

- a) Draw the waveforms of the current and voltage related to T1, D2 and Cs. Assume the T1 current turn-off to be instantaneous as shown above. The snubber capacitor is initially charged to $U_c = U_d$ at the instant of T1 turn-off.
- b) Calculate the required snubber capacitance in order to limit the over voltage to 20% when T1 is turned off. (6)



Formula collection TSTE19 Power Electronics

Fourier series coefficients using symmetry,

Even
$$f(-t) = f(t) b_h = 0 a_h = \frac{2}{\pi} \int_0^{\pi} f(t) cos(h\omega t) d(\omega t)$$

Odd
$$f(-t) = -f(t) a_h = 0 b_h = \frac{2}{\pi} \int_0^{\pi} f(t) \sin(h\omega t) d(\omega t)$$

Half-wave
$$f(t) = -f(t + \frac{1}{2}T)$$
 $a_h = b_h = 0$ for even h

$$a_h = \frac{2}{\pi} \int_0^{\pi} f(t) cos(h\omega t) d(\omega t)$$
 for odd h

$$b_h = \frac{2}{\pi} \int_0^{\pi} f(t) sin(h\omega t) d(\omega t)$$
 for odd h

Even quart-wave Even and half-wave
$$b_h = 0$$
 for all h

$$a_h = \frac{4}{\pi} \int_0^{\frac{\pi}{2}} f(t) cos(h\omega t) d(\omega t)$$
 for odd h, $a_h = 0$ for even h

Odd quarter-wave Odd and half-wave
$$a_h = 0$$
 for all h

$$b_h = \frac{4}{\pi} \int_0^{\frac{\pi}{2}} f(t) \sin(h\omega t) d(\omega t)$$
 for odd h, $b_h = 0$ for even h

Undamped resonant circuits

Even
$$f(-t) = f(t)$$
 $b_h = 0$ $a_h = \frac{2}{\pi} \int_0^{\pi} f(t) cos(h\omega t) d(\omega t)$

Odd
$$f(-t) = -f(t)$$
 $a_h = 0$ $b_h = \frac{2}{\pi} \int_0^{\pi} f(t) \sin(h\omega t) d(\omega t)$

Half-wave
$$f(t) = -f\left(t + \frac{1}{2}T\right) \quad a_h = b_h = 0 \text{ for even h}$$

$$a_h = \frac{2}{\pi} \int_0^{\pi} f(t) cos(h\omega t) d(\omega t)$$
 for odd h

$$b_h = \frac{2}{\pi} \int_0^{\pi} f(t) sin(h\omega t) d(\omega t)$$
 for odd h

Even quart-wave Even and half-wave
$$b_h = 0$$
 for all h

$$a_h = \frac{4}{\pi} \int_0^{\frac{\pi}{2}} f(t) cos(h\omega t) d(\omega t)$$
 for odd h, $a_h = 0$ for even h

Odd quarter-wave Odd and half-wave
$$a_h=0$$
 for all h

$$b_h=\frac{4}{\pi}\int_0^{\frac{\pi}{2}}f(t)sin(h\omega t)d(\omega t)$$
 for odd h, $b_h=0$ for even h

Integration rules

$$\int_a^b f(x) dx = \int_A^B f(g(t)) g'(t) dt$$
 if $a = g(A), \, b = g(B)$ and g is monotone in [A,B]

$$\int_{a}^{b} \sin(x)dx = \left[-\cos(x)\right]_{a}^{b}$$

$$\int_{a}^{b} \cos(x) dx = \left[\sin(x) \right]_{a}^{b}$$

